

**WBA0003B****1 kHz – 300 MHz LOW NOISE WIDE BAND AMPLIFIER****REV A**
July 2012

Key Features



- 50-Ohm Impedance
- 1 kHz ~ 300 MHz
- 1.25 dB noise figure
- 15.0 dB Gain
- +/-0.25 dB Gain Flatness
- 12.0 dBm P_{1dB}
- 20 dB Return Loss
- Single Power Supply
- >68 years MTBF
- Unconditional stable
- RoHS Compliant

Product Description

WBA0003B integrates WanTcom proprietary low noise amplifier technology, high frequency micro electronic assembly techniques, and high reliability design to realize optimum low noise figure, wideband, high linearity, and unconditional stable performances together. With single +5.0V DC operation, the amplifier has optimal input and output matching in the specified frequency range at 50-Ohm impedance system. The amplifier has standard SMA connectorized WP-5 gold plated housing.

The amplifier is designed to meet the rugged standard of MIL-STD-202.

Applications

- Mobile Infrastructures
- Broadcast
- CATV/DBS
- Defense
- Security System
- Measurement
- Fixed Wireless



Specifications

Summary of the electrical specifications WBA0003B at room temperature

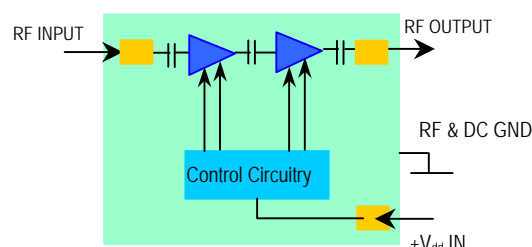
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S ₂₁	1 kHz – 300 MHz		15		dB
2	Gain Variation	ΔG	1 kHz – 300 MHz		+/- 0.25	+/-0.5	dB
3	Input Return Loss	S ₁₁	1 kHz – 300 MHz	14	20		dB
4	Output Return Loss	S ₂₂	1 kHz – 300 MHz	14	22		dB
5	Reverse Isolation	S ₁₂	1 kHz – 300 MHz		20		dB
6	Noise figure	NF	50 MHz – 300 MHz		1.25	1.50	dB
			10 MHz – 50 MHz			2.6	dB
7	Output Power 1dB compression Point	P _{1dB}	1 kHz – 300 MHz		12		dBm
9	Current Consumption	I _{dd}	V _{dd} = +5 V		45		mA
10	Power Supply Voltage	V _{dd}		+4.7	+5	+5.2	V
11	Thermal Resistance	R _{th,c}	Junction to case, 2 nd stage, 30 mA@3.0V			220	°C/W
12	Operating Temperature	T _o		-40		+85	°C
13	Maximum Average RF Input Power	P _{IN, MAX}	1 kHz – 300 MHz			10	dBm

Absolute Maximum Ratings

Parameters	Units	Ratings
DC Power Supply Voltage	V	7.0
Drain Current	mA	70
Input and Output DC Voltage	V	10
RF Input Power	dBm	0
Channel Temperature	°C	150
Storage Temperature	°C	-65 ~ 150
Operating Temperature	°C	-55 ~ 100
Thermal Resistance	°C/W	220

Operation of this device above any one of these parameters may cause permanent damage.

Functional Block Diagram



Ordering Information

Model Number	WBA0003B
--------------	----------

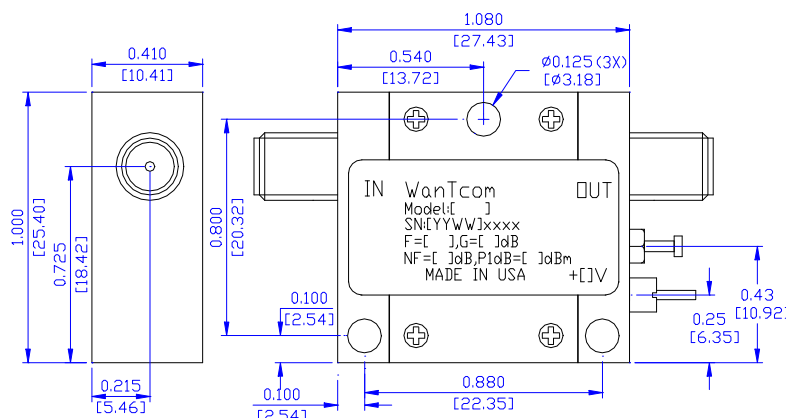
Specifications and information are subject to change without notice.

WanTcom, Inc * Phone 01 952 448 6088 * FAX: 01 952 448 7188 * e-mail: sales@wantcominc.com * Web site: www.wantcominc.com

Typical Data

Outline, WP-5 Housing

UNITS:	INCH
	[mm]
BODY:	Brass
Finish:	Gold Plating
RF Connector:	SMA F Gold
V _{dd} PWR:	Feed through



Application Notes:

A. SMA Torque Wrench Selection

Always use a torque wrench with 5 ~ 6 inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

B. DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.
